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Direct Imaging of Graphene Edges: Atomic Structure and Electronic Scattering

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Supporting Information

ABSTRACT: We report an atomically resolved scanning tunneling microscopy investigation of the edges of graphene grains synthesized on Cu foils by chemical vapor deposition. Most of the edges are macroscopically parallel to the zigzag directions of graphene lattice. These edges have microscopic roughness that is found to also follow zigzag directions at atomic scale, displaying many ~120° turns. A prominent standing wave pattern with periodicity ~3a/4 (a being the graphene lattice constant) is observed near a rare-occurring armchair-oriented edge. Observed features of this wave pattern are consistent with the electronic intervalley backscattering predicted to occur at armchair edges but not at zigzag edges.

KEYWORDS: Graphene, STM, edge, zigzag, armchair, electronic scattering

Graphene edges are fundamentally interesting and can display rich behavior dependent on their atomic arrangements. The two most basic configurations of graphene edges, “zigzag” and “armchair,” are defined in terms of their orientations along graphene’s two major crystallographic directions. These two prototypes of graphene edges have been predicted to have very different electronic properties that could be important for nanoelectronic applications. For example, theories predict that zigzag edges exhibit a characteristic edge state (absent in armchair edges) that can give rise to novel electronic and magnetic properties of graphene nanoribbons (GNRs) with zigzag edges. The electronic scattering at armchair and zigzag edges are also markedly different. It has been suggested that armchair edges give rise to intervalley backscattering, which is suppressed at zigzag edges. While edges that display macroscopic orientations parallel to either zigzag or armchair crystallographic directions are commonly observable, for example, in exfoliated graphene sheets, such (macroscopically oriented) zigzag or armchair edges are generally expected to have microscopic edge roughness (deviation from perfect zigzag or armchair edges), which can have important implications for experiments and applications involving graphene nanostructures.

Scanning tunneling microscopy (STM) is a powerful tool to characterize the local structural and electronic properties of graphene down to atomic scale. However, it has been challenging to perform atomically resolved STM imaging of edges of a single layer graphene to clearly demonstrate their atomic structures and orientation dependent electronic properties. In this report, we present atomically resolved STM images showing unprecedented details of the atomic structure and roughness of zigzag edges in chemical vapor deposited graphene single crystal grains grown on Cu foils. We also observe a striking standing wave pattern parallel to an armchair edge with features consistent with the electronic intervalley backscattering expected to occur at armchair but not zigzag edges.

Our studies were performed on hexagonally shaped graphene grains (with typical size of several micrometers or bigger) synthesized ex situ by ambient chemical vapor deposition (CVD) on Cu foils (see Supporting Information). Our previous work has shown that such grains are monolayer single crystalline graphene with edges predominantly exhibiting macroscopic orientations parallel to zigzag directions. In the current work, such graphene grains as-grown on Cu substrates are placed in an UHV (ultrahigh vacuum) STM system and annealed at ~400 °C for 48 h before STM is performed at room temperature (see Supporting Information).

Figure 1a shows a large-scan-area STM topographic image taken near two edges (highlighted by dashed lines, forming an angle of ~120°) of one such graphene grain. The atomically resolved image (inset) acquired from inside the grain (from the area indicated by dotted black box in Figure 1a) exhibits characteristic honeycomb lattice of single layer graphene. From such a lattice image we infer the two edges in Figure 1a are (macroscopically) oriented along zigzag directions. Figure 1b is a
Figure 1. (a) STM topographic image of a graphene grain near 2 zigzag-oriented edges (dashed white lines). Measurement condition: tunneling current $I = 0.1 \text{ nA}$, sample-tip bias voltage $V = -0.2 \text{ V}$. The lines texture (spacing $\sim 4.5 \text{ nm}$) seen on graphene is attributed to features on Cu surface underneath graphene and not the focus of this paper. Inset (scale bar = 2.4 Å) shows representative atomically resolved image of graphene lattice inside the grain taken from the area indicated by the black dotted box ($I = 20 \text{ nA}, V = -0.2 \text{ V}$). (b) A magnified image, acquired from the red dotted boxed area in (a), showing the graphene edge with microscopic roughness ($I = 20 \text{ nA}, V = -0.2 \text{ V}$). Arrows indicate the three zigzag directions in graphene lattice. (c,d) Representative atomically resolved images of the graphene edge taken from the blue dotted boxed area in (a) and black dashed boxed area in (b), respectively, showing its roughness typically follows zigzag directions ($I = 20 \text{ nA}, V = -0.2 \text{ V}$). A few model hexagons of graphene lattice are superimposed on the image. Dashed white lines mark the general contour of the edge. The Cu surface not covered (and protected) by graphene is oxidized and the topographic depression (dark area) just outside graphene (within $\sim 1 \text{ nm}$ from the graphene edge) is interpreted as due to less coverage of Cu oxide immediately near graphene.
Figure 2. (a) STM topographic image showing two zigzag-oriented edges and a rare-occurring armchair-oriented edge ($I = 0.1 \text{ nA}, V = -0.2 \text{ V}$). Magnified images of the dotted red and green boxes are presented in (b) and Supporting Information Figure S2a, respectively. (b) A 3D rendition of atomic-resolved topographic image acquired from the red box (15.4 nm by 15.4 nm) in (a), showing a standing wave pattern near the armchair edge ($I = 10 \text{ nA}, V = -0.2 \text{ V}$). Dotted and dashed lines mark the armchair (‘A’, whose precise location is obscured by the standing wave pattern) and zigzag (‘Z’) edges. (c) A zoomed-in image near the armchair edge ($I = 10 \text{ nA}, V = 0.2 \text{ V}$) with superimposed models for part of the graphene lattice (hexagons, lattice constant $a$) and the standing wave pattern (dashed lines, period $\lambda$).

Although the dominant majority of the edges in our graphene grains are found to be zigzag-oriented, we did observe one rare-occurring armchair-oriented edge (labeled by the dotted line in Figure 2a, forming $\sim 30^\circ$ angle with two nearby zigzag-oriented edges labeled by dashed lines). This is so far the only armchair edge we found in our STM experiments, despite our efforts to search for more. Figure 2b shows a three-dimensional (3D) rendition of a high-resolution STM topographic image acquired from the area indicated by the dotted red box in Figure 2a. We observe a striking standing wavelike pattern parallel to the armchair edge (dotted white line, where the wave pattern has made it difficult to image the armchair edge itself at atomic scale). In contrast, such a wave pattern is not observed (within our imaging resolution) near the zigzag edge in Figure 2b (dashed white line) or any other zigzag edges we have imaged (Figure 1 and Supporting Information Figure S1). Figure 2c shows a representative atomically resolved image taken near the armchair edge, showing the periodicity ($\lambda$) of the wave pattern (dashed black lines) is approximately $3a/4$ with $a$ being the graphene lattice constant (see Supporting Information). This periodicity corresponds to a wavevector of $2\pi/\lambda \sim 8\pi/3a$. Figure 3a shows the Fourier transform (FT) of Figure 2c, where the FT of the wave pattern gives rise to the two spots labeled by the red circles. These two spots can be identified with the “2K” points in the momentum-space model of graphene in Figure 3b (which also shows the Dirac “K”-points as labeled by dashed red circles and the reciprocal lattice (RL, FT of graphene lattice) points, as labeled by solid black circles and corresponding to the 6-fold-symmetric spots in Figure 3a. The extracted length ratio between the vectors “RL” and “2K” labeled in Figure 3a is $\sim 0.82$. The extracted ratio ($\lambda/a$) between the periodicity ($\lambda$) of the observed wave pattern and graphene lattice constant ($a$) is $\lambda/a \sim 0.73$ (by averaging over different areas of the real space STM images, Figure 2c and Supporting Information Figure S2a). Both these values are in excellent agreement with the theoretical value of RL/2K = $\sqrt{3}/2$ ($\sim 0.866$) and (2$\pi$/2K)/a = $3/4$ (where $2\pi/2K$ is the wavelength corresponding to a wavevector 2K), within our experimental uncertainty (mainly due to tip scan hysteresis and sample/tip drift resulting in a slight distortions in our STM images).

It is well-known that STM is sensitive to the local electronic density of states (DOS) and standing wave patterns resulted from electronic scattering are often revealed (even at room temperatures) in STM topographs. While more work is needed to confirm whether the standing wave pattern observed at the sole armchair edge we found in our samples is a generic phenomenon for armchair edges in graphene, several features including the direction (normal to the armchair), periodicity ($\sim 3a/4$) and wavevector ($\sim 2K = 8\pi/3a$) of the standing wave pattern shown in Figure 2 are all consistent with a predicted intervalley backscattering induced by the armchair edge. Such an intervalley backscattering connects two Dirac cones (Figure 3c, “K” and “-K”, where the length of the “K” vector is the $\Gamma K$ distance = $4\pi/3a$) oppositely located from $\Gamma$ point in the momentum space (Figure 3b), corresponding to a scattering...
wavevector of $2K$. Several Raman spectroscopy studies$^{7,9,26}$ of graphene edges have suggested$^7$ that an armchair edge (terminated by both “A” and “B” sublattice sites, Figure 3d) induces strong intervalley backscattering, as the backscattering direction (normal to the edge) is well aligned with an intervalley scattering wavevector ($2K$). In contrast, intervalley backscattering is suppressed at a zigzag edge (terminated by “A” sites only) as such an alignment does not occur (instead the backscattering direction makes a $30^\circ$ angle with a $2K$ vector). In our experiments, the standing wave pattern shown in Figure 2 was only observed at this armchair edge. It was not observed at any of the (many) zigzag edges we studied nor in any other regions inside graphene grains or on Cu surfaces (including at Cu surface steps), thus unlikely to be associated with some random topography features (unrelated to armchair edges) of graphene or Cu surfaces. It is also unlikely to be related to the $2k_F$ Friedel oscillations of Cu surface states, observed previously by low-temperature STM on single crystalline Cu, for example, at surface steps,$^{34,25}$ with an oscillation periodicity ($\sim 1.5$ nm) much larger than ours. Taken together, these considerations are highly suggestive that the observed standing wave pattern is related with the intervalley backscattering expected to occur at the armchair edge of graphene. STM imaging can thus provide a clear demonstration of the remarkable difference in the electronic scattering properties between armchair and zigzag edges previously suggested by Raman studies.

Recently, a scattering pattern with wavevector close to $K$ (periodicity $\sim 2\pi/K = 3a/2$) has been observed by STM near armchair-oriented edges of graphene grown on SiC (0001)$^{23}$ The authors$^{23}$ also related this scattering pattern with intervalley backscattering, and attributed the apparent “doubling” of the observed periodicity (from the expected $2\pi/2K$ for intervalley backscattering) as due to the localization of electronic DOS along the C–C bonds in graphene, resulting in the “missing” of every other oscillation. In comparison, our observed scattering pattern has wavevector $\sim 2K$ (periodicity $\sim 2\pi/2K$), as expected for intervalley backscattering. We suggest that this difference may be related to the different substrates, which can have important influence on electronic properties of graphene. In our case, the metallic Cu substrate may have played some role to enable the full oscillations of intervalley backscattering in graphene (periodicity $2\pi/2K$, half that observed in ref 23) to be observed. More work is needed to understand this effect in detail. We note that no clear observation of intervalley backscattering patterns have been obtained in previous STM measurements on armchair edges of nanometer-sized graphene islands$^{17,21}$ probably due to the obscuring effect of interfering multiple scatterings from edges of different directions in such small size systems. The short
“propagation distance” (on the order of a few nanometers, beyond which the oscillation is no longer discernible) of the wave pattern we observed (Figure 2b,c) may be generally attributed to thermally induced dephasing of electrons in such room temperature measurements.23

CVD of graphene on Cu foils has emerged as one of the most promising routes to scalable production of graphene for a wide range of applications.27,28 STM studies can be highly valuable to understand the growth mechanism of such CVD graphene and its structural and electronic properties at atomic scale. Such a system is also particularly convenient to perform fundamental STM studies of graphene as single layer graphene can be easily synthesized on Cu substrates, which only weakly interacts with (and perturbs) graphene11,29 while providing a highly conductive substrate facilitating STM of graphene and its edges.

Atomically resolved images of graphene edges and edge roughness such as those shown in this work (Figure 1 and Supporting Information Figure S1) could provide a precise characterization of the disorder due to edge roughness that can strongly affect the behavior of graphene nanoelectronic devices.10 It is interesting to note that, despite their microscopic roughness, the zigzag-oriented edges (whose global and local orientations both follow zigzag directions) of our graphene grains do not appear to scatter electrons strongly, enabling the atomic structure of such edges to be well resolved without being masked by scattering patterns (in contrast to the armchair edge in Figure. 2). Such “zigzag roughened” edges (largely free of electronic scattering) found in our CVD graphene on Cu have not been reported in previous STM studies of the edges in other forms of stand-alone graphene,17–21 or graphene-on-graphite,30–32 and may possess distinctive electronic properties and promise for device applications.

**REFERENCES**


